Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Glass **Overall Length:** 0.180 inches **Terminal Length:** 1.250 inches **Overall Diameter:** 0.075 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: -40.0 breakdown voltage, dc and 0.9 forward voltage, peak **Current Rating Per Characteristic:** 50.00 microamperes forward current, average major **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0